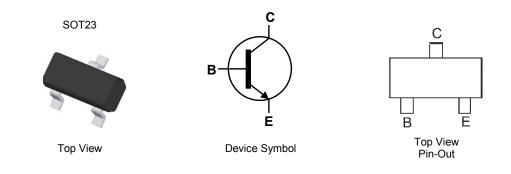


Features

- BV_{CEO} > 50V
- I_C = 150mA Collector Current
- Low Saturation Voltage V_{CE(sat)} < 400mV @ 50mA
- Epitaxial Planar Die Construction
- Ideal for Medium Power Amplification and Switching
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen, Antimony and Beryllium-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/guality/product-definitions/</u>

Mechanical Data

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.008 grams (approximate)



Ordering Information (Note 4)

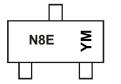
Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
2DC2412R-7	Standard	N8E	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Balogen, Antimony and Beryllium-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl), <1000ppm antimony compounds and <1000ppm Beryllium.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



N8E = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

Notes:

Year	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	1	J	K	L	М	N	0	Р	R	S	Т	U
Month	Jan	Feb	Mar	Apr	Mav	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Lead-free.



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

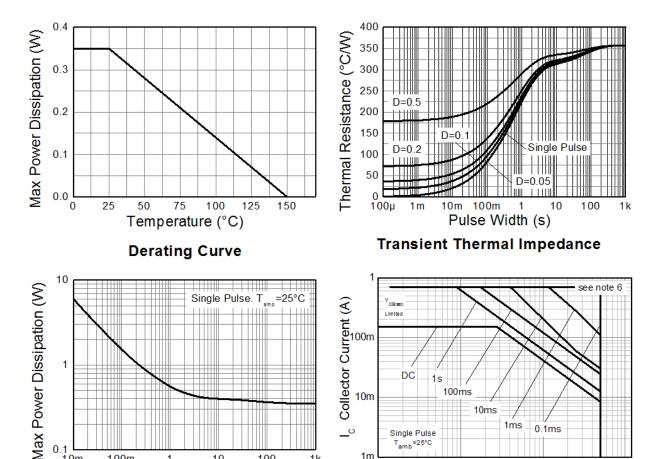
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	7.0	V
Continuous Collector Current	lc	150	mA

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Dewer Dissinction	(Note 5)		310	m\\/	
Power Dissipation	(Note 6)	P _D	350	mW	
Thermal Desistance, lunction to Ambient	(Note 5)	P	403	°CAN/	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	357	°C/W	
Thermal Resistance, Junction to Leads	(Note 7)	R _{θJL}	350	°C/W	
Operating and Storage Temperature Range	T _J ,T _{STG}	-55 to +150	°C		

Notes:

5. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper, in still air conditions. 6. For the device mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions. 7. Thermal resistance from junction to solder-point (at the end of the leads).



0.1 L 10m

100m

1

10

Pulse Width (s) **Pulse Power Dissipation**

100

1k

1m _____ 100m

V_{cE} Collector-Emitter Voltage (V)

Safe Operating Area

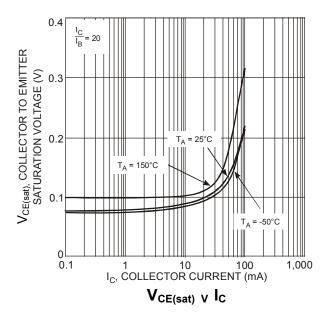
100

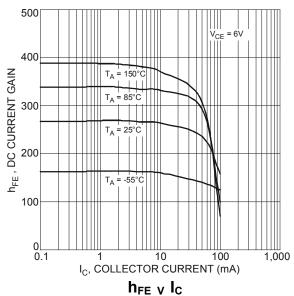


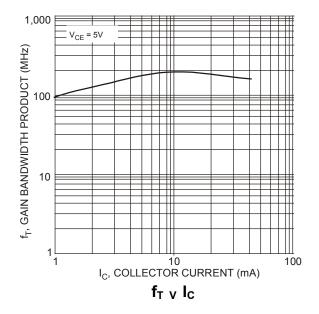
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
DFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	60		_	V	I _C = 100μA, I _E = 0
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	50		_	V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	7.0		_	V	I _E = 100μA, I _C = 0
Collector Cutoff Current	I _{CBO}	_		100	nA	V _{CB} = 60V
Base Cutoff Current	I _{EBO}	_		100	nA	V _{EB} = 6.0V
ON CHARACTERISTICS (Note 8)						•
DC Current Gain	h _{FE}	180	_	390	_	$I_{C} = 1.0 \text{mA}, V_{CE} = 6.0 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	0.2	0.4	V	I _C = 50mA, I _B = 5.0mA
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C _{obo}	_	2.0	3.5	pF	$V_{CB} = 5.0V, f = 1.0MHz, I_E = 0$
Transition Frequency	f⊤	80	180	_	MHz	V _{CE} = 12V, I _C = 2mA, f = 100MI

Note: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



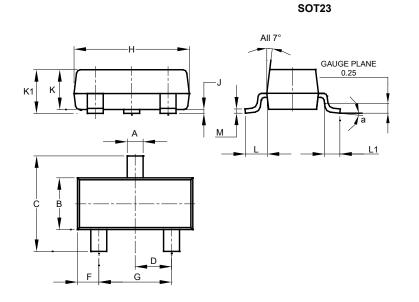






Package Outline Dimensions

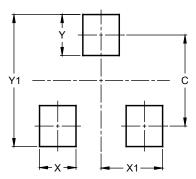
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23						
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
ĸ	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

SOT23



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